FEATURES

- High Bandwidth:
  - 325 MHz in Unity Gain
  - 210 MHz Gain Bandwidth Product
- High Slew Rate:
  - 900 V/μs (G = 2)
  - 1000 V/μs (G = 5)
- Low Distortion of –76 dB, SFDR at 5 MHz
- Maximum Input Bias Current: 100 pA
- Input Voltage Noise: 7 nV/√Hz
- Maximum Input Offset Voltage: 500 μV at 25°C
- Low Offset Drift: 2.5 μV/°C
- Wide Supply Range: ± 5 V to ± 15 V
- High Output Current: 95 mA

APPLICATIONS

- Wideband Photodiode Amplifier
- High-Speed Transimpedance Gain Stage
- Test and Measurement Systems
- Current-DAC Output Buffer
- Active Filtering
- High-Speed Signal Integrator
- High-Impedance Buffer

DESCRIPTION

The THS4631 is a high-speed, FET-input operational amplifier designed for applications requiring wideband operation, high-input impedance, and high-power supply voltages. By providing a 210-MHz gain bandwidth product, ±15-V supply operation, and 100-pA input bias current, the THS4631 is capable of simultaneous wideband transimpedance gain and large output signal swing. The fast 1000 V/μs slew rate allows for fast settling times and good harmonic distortion at high frequencies. Low current and voltage noise allow amplification of extremely low-level input signals while still maintaining a large signal-to-noise ratio.

The characteristics of the THS4631 make it ideally suited for use as a wideband photodiode amplifier. Photodiode output current is a prime candidate for transimpedance amplification as shown below. Other potential applications include test and measurement systems requiring high-input impedance, ADC and DAC buffering, high-speed integration, and active filtering.

The THS4631 is offered in an 8-pin SOIC (D), and the 8-pin SOIC (DDA) and MSOP (DGN) with PowerPAD™ package.

<table>
<thead>
<tr>
<th>DEVICE</th>
<th>Vss (V)</th>
<th>GBWP (MHz)</th>
<th>SLEW RATE (V/μS)</th>
<th>VOLTAGE NOISE (nV/√Hz)</th>
<th>MINIMUM GAIN</th>
</tr>
</thead>
<tbody>
<tr>
<td>OPA656</td>
<td>±5</td>
<td>230</td>
<td>290</td>
<td>7</td>
<td>1</td>
</tr>
<tr>
<td>OPA657</td>
<td>±5</td>
<td>1600</td>
<td>700</td>
<td>4.8</td>
<td>7</td>
</tr>
<tr>
<td>OPA627</td>
<td>±15</td>
<td>16</td>
<td>55</td>
<td>4.5</td>
<td>1</td>
</tr>
<tr>
<td>THS4601</td>
<td>±15</td>
<td>180</td>
<td>100</td>
<td>5.4</td>
<td>1</td>
</tr>
</tbody>
</table>

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PowerPad is a trademark of Texas Instruments.
This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### ABSOLUTE MAXIMUM RATINGS

**over operating free-air temperature range (unless otherwise noted)**

<table>
<thead>
<tr>
<th>Parameter</th>
<th>UNITS</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_S$ Supply voltage, $V_S$ to $V_S+$</td>
<td>33 V</td>
</tr>
<tr>
<td>$V_I$ Input voltage</td>
<td>$\pm V_S$</td>
</tr>
<tr>
<td>$I_O$ (2) Output current</td>
<td>150 mA</td>
</tr>
<tr>
<td>Continuous power dissipation</td>
<td>See Dissipation Rating Table</td>
</tr>
<tr>
<td>$T_J$ Maximum junction temperature (2)</td>
<td>150°C</td>
</tr>
<tr>
<td>$T_A$ Operating free-air temperature, continues operation, long-term reliability (2)</td>
<td>125°C</td>
</tr>
<tr>
<td>$T_{stg}$ Storage temperature range</td>
<td>–65°C to 150°C</td>
</tr>
</tbody>
</table>

**ESD ratings:**

- HBM
- CDM
- MM

(1) The absolute maximum ratings under any condition is limited by the constraints of the silicon process. Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

(2) The maximum junction temperature for continuous operation is limited by package constraints. Operation above this temperature may result in reduced reliability and/or lifetime of the device.

### PACKAGE DISSIPATION RATINGS

<table>
<thead>
<tr>
<th>PACKAGE</th>
<th>$\theta_{JC}$ (°C/W)</th>
<th>$\theta_{JA}$ (°C/W)</th>
<th>POWER RATING$^{(1)}$ ($T_J=125°C$)</th>
</tr>
</thead>
<tbody>
<tr>
<td>D (8) (2)</td>
<td>38.3</td>
<td>95</td>
<td>$T_A \leq 25°C$ 1.1 W 0.47 W</td>
</tr>
<tr>
<td>DDA (8)</td>
<td>9.2</td>
<td>45.8</td>
<td>$T_A = 85°C$ 2.3 W 0.98 W</td>
</tr>
<tr>
<td>DGN (8)</td>
<td>4.7</td>
<td>58.4</td>
<td>2.14 W 1.11 W</td>
</tr>
</tbody>
</table>

(1) Power rating is determined with a junction temperature of 125°C. This is the point where distortion starts to substantially increase. Thermal management of the final PCB should strive to keep the junction temperature at or below 125°C for best performance.

(2) This data was taken using the JEDEC standard High-K test PCB.

### RECOMMENDED OPERATING CONDITIONS

**over operating free-air temperature range (unless otherwise noted)**

<table>
<thead>
<tr>
<th>Parameter</th>
<th>MIN</th>
<th>MAX</th>
<th>UNITS</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_S$ Supply Voltage</td>
<td>$\pm5$</td>
<td>$\pm15$</td>
<td>V</td>
</tr>
<tr>
<td>Single Supply</td>
<td>10</td>
<td>30</td>
<td></td>
</tr>
<tr>
<td>$T_A$ Operating free-air temperature</td>
<td>-40</td>
<td>85</td>
<td>°C</td>
</tr>
</tbody>
</table>

(1) Copyright © 2004–2011, Texas Instruments Incorporated
PACKAGE / ORDERING INFORMATION

<table>
<thead>
<tr>
<th>PACKAGE DEVICES(1)</th>
<th>PACKAGE TYPE SOIC – 8</th>
<th>TRANSPORT MEDIA, QUANTITY</th>
</tr>
</thead>
<tbody>
<tr>
<td>THS4631D</td>
<td>SOIC – 8</td>
<td>Rails, 75</td>
</tr>
<tr>
<td>THS4631DR</td>
<td>SOIC-PP – 8(2)</td>
<td>Tape and Reel, 2500</td>
</tr>
<tr>
<td>THS4631DDA</td>
<td>SOIC-PP – 8(2)</td>
<td>Rails, 75</td>
</tr>
<tr>
<td>THS4631DDAR</td>
<td>MSOP-PP – 8(2)</td>
<td>Tape and Reel, 2500</td>
</tr>
<tr>
<td>THS4631DGN</td>
<td>MSOP-PP – 8(2)</td>
<td>Rails, 100</td>
</tr>
<tr>
<td>THS4631DGNR</td>
<td>MSOP-PP – 8(2)</td>
<td>Tape and Reel, 2500</td>
</tr>
</tbody>
</table>

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

(2) PowerPad™ is electrically isolated from all other pins. Connection of the PowerPAD to the PCB ground plane is recommended because the ground plane is typically the largest copper area on a PCB. However, connection of the PowerPAD to V_{S-} up to V_{S+} is allowed if desired.

PIN ASSIGNMENTS

```
TOP VIEW
THS4631
D, DDA, AND DGN

NC  1 NC
V_{IN-}  2 V_{S+}
V_{IN+}  3 V_{OUT-}
V_{S-}  4 NC

NC = No Internal Connection
```
### ELECTRICAL CHARACTERISTICS

\[ V_S = \pm 15 \text{ V}, \; R_F = 499 \Omega, \; R_L = 1 \text{ k}\Omega, \text{ and } G = 2 \text{ (unless otherwise noted)} \]

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>TEST CONDITIONS</th>
<th>TYP</th>
<th>OVER TEMPERATURE</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td></td>
<td>25°C</td>
<td>25°C</td>
</tr>
<tr>
<td>AC PERFORMANCE</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Small signal bandwidth, -3 dB</td>
<td>( G = 1, R_F = 0 \Omega, V_O = 200 \text{ mVpp} )</td>
<td>325</td>
<td></td>
</tr>
<tr>
<td></td>
<td>( G = 2, R_F = 499 \Omega, V_O = 200 \text{ mVpp} )</td>
<td>105</td>
<td></td>
</tr>
<tr>
<td></td>
<td>( G = 5, R_F = 499 \Omega, V_O = 200 \text{ mVpp} )</td>
<td>55</td>
<td></td>
</tr>
<tr>
<td></td>
<td>( G = 10, R_F = 499 \Omega, V_O = 200 \text{ mVpp} )</td>
<td>25</td>
<td></td>
</tr>
<tr>
<td>Gain bandwidth product</td>
<td>( G &gt; 20 )</td>
<td>210</td>
<td></td>
</tr>
<tr>
<td>0.1 dB bandwidth flatness</td>
<td>( G = 2, R_F = 499 \Omega, Vo = 2 \text{ Vpp} )</td>
<td>38</td>
<td></td>
</tr>
<tr>
<td>Large-signal bandwidth</td>
<td>( G = 2, R_F = 499 \Omega, V_O = 2 \text{ Vpp} )</td>
<td>105</td>
<td></td>
</tr>
<tr>
<td>Slew rate</td>
<td>( G = 2, R_F = 499 \Omega, V_O = 2 \text{ V step} )</td>
<td>550</td>
<td></td>
</tr>
<tr>
<td></td>
<td>( G = 5, R_F = 499 \Omega, V_O = 10 \text{ V step} )</td>
<td>900</td>
<td></td>
</tr>
<tr>
<td></td>
<td>( G = 5, R_F = 499 \Omega, V_O = 10 \text{ V step} )</td>
<td>1000</td>
<td></td>
</tr>
<tr>
<td>Rise and fall time</td>
<td>2-V step</td>
<td>5</td>
<td></td>
</tr>
<tr>
<td>Settling time</td>
<td>( 0.1%, G = -1, V_O = 2 \text{ V step}, C_F = 4.7 \text{ pF} )</td>
<td>40</td>
<td></td>
</tr>
</tbody>
</table>

### HARMONIC DISTORTION

<table>
<thead>
<tr>
<th></th>
<th>( R_L = 100 \Omega )</th>
<th>-85</th>
<th>dBc</th>
<th>( R_L = 1 \text{ k}\Omega )</th>
<th>-76</th>
<th>dBc</th>
</tr>
</thead>
<tbody>
<tr>
<td>Second harmonic distortion</td>
<td>( G = 2, ; V_O = 2 \text{ Vpp}, ; f = 5 \text{ MHz} )</td>
<td></td>
<td></td>
<td>Third harmonic distortion</td>
<td>( G = 2, ; V_O = 2 \text{ Vpp}, ; f = 5 \text{ MHz} )</td>
<td></td>
</tr>
<tr>
<td></td>
<td>( R_L = 100 \Omega )</td>
<td>-62</td>
<td>dBc</td>
<td>( R_L = 1 \text{ k}\Omega )</td>
<td>-94</td>
<td>dBc</td>
</tr>
</tbody>
</table>

### DC PERFORMANCE

<table>
<thead>
<tr>
<th></th>
<th>( R_L = 1 \text{ k}\Omega )</th>
<th>80</th>
<th>70</th>
<th>65</th>
<th>65</th>
<th>dB</th>
<th>Min</th>
</tr>
</thead>
<tbody>
<tr>
<td>Open-loop gain</td>
<td>( V_{CM} = 0 \text{ V} )</td>
<td>260</td>
<td>500</td>
<td>1600</td>
<td>2000</td>
<td>( \mu V )</td>
<td>Max</td>
</tr>
<tr>
<td>Average offset voltage drift(^1) ( 25°C ) to 85°C</td>
<td>( \pm 2.5 )</td>
<td>( \pm 10 )</td>
<td>( \pm 12 )</td>
<td>( \pm 12 )</td>
<td>( \mu V/°C )</td>
<td>Max</td>
<td></td>
</tr>
<tr>
<td>Input bias current</td>
<td>( V_{CM} = 0 \text{ V} )</td>
<td>50</td>
<td>100</td>
<td>1500</td>
<td>2000</td>
<td>pA</td>
<td>Max</td>
</tr>
<tr>
<td>Input offset current</td>
<td>( V_{CM} = 0 \text{ V} )</td>
<td>25</td>
<td>100</td>
<td>700</td>
<td>1000</td>
<td>pA</td>
<td>Max</td>
</tr>
</tbody>
</table>

### INPUT CHARACTERISTICS

<table>
<thead>
<tr>
<th></th>
<th>( V_{CM} = 10 \text{ V} )</th>
<th>95</th>
<th>86</th>
<th>80</th>
<th>80</th>
<th>dB</th>
<th>Min</th>
</tr>
</thead>
<tbody>
<tr>
<td>Common-mode input range</td>
<td>( V_{CM} = 0 \text{ V} )</td>
<td>10(^3)</td>
<td>3.9</td>
<td></td>
<td></td>
<td>( \Omega )</td>
<td>pF</td>
</tr>
<tr>
<td>Common-mode rejection ratio</td>
<td>( V_{CM} = 0 \text{ V} )</td>
<td>10(^3)</td>
<td>3.9</td>
<td></td>
<td></td>
<td>( \Omega )</td>
<td>pF</td>
</tr>
</tbody>
</table>

### OUTPUT CHARACTERISTICS

<table>
<thead>
<tr>
<th></th>
<th>( R_L = 100 \Omega )</th>
<th>±11</th>
<th>±10</th>
<th>±9.5</th>
<th>±9.5</th>
<th>V</th>
<th>Min</th>
</tr>
</thead>
<tbody>
<tr>
<td>Output voltage swing</td>
<td>( R_L = 1 \text{ k}\Omega )</td>
<td>±13.5</td>
<td>±13</td>
<td>±12.8</td>
<td>±12.8</td>
<td>V</td>
<td>Min</td>
</tr>
<tr>
<td>Static output current (sourcing)</td>
<td>( R_L = 20 \Omega )</td>
<td>98</td>
<td>90</td>
<td>85</td>
<td>80</td>
<td>mA</td>
<td>Min</td>
</tr>
<tr>
<td>Static output current (sinking)</td>
<td>( R_L = 20 \Omega )</td>
<td>95</td>
<td>85</td>
<td>80</td>
<td>80</td>
<td>mA</td>
<td>Min</td>
</tr>
<tr>
<td>Closed loop output impedance</td>
<td>( G = 1, f = 1 \text{ MHz} )</td>
<td>0.1</td>
<td></td>
<td></td>
<td></td>
<td>( \Omega )</td>
<td></td>
</tr>
</tbody>
</table>

### POWER SUPPLY

<table>
<thead>
<tr>
<th></th>
<th>±15</th>
<th>±16.5</th>
<th>±16.5</th>
<th>±16.5</th>
<th>V</th>
<th>Max</th>
</tr>
</thead>
<tbody>
<tr>
<td>Specified operating voltage</td>
<td>±5</td>
<td>±4</td>
<td>±4</td>
<td>±4</td>
<td>V</td>
<td>Min</td>
</tr>
<tr>
<td>Maximum quiescent current</td>
<td>11.5</td>
<td>13</td>
<td>14</td>
<td>14</td>
<td>mA</td>
<td>Max</td>
</tr>
<tr>
<td>Minimum quiescent current</td>
<td>11.5</td>
<td>10</td>
<td>9</td>
<td>9</td>
<td>mA</td>
<td>Min</td>
</tr>
<tr>
<td>Power supply rejection (PSRR +)</td>
<td>( V_{SS} = 15.5 \text{ V to 14.5 V}, V_{SL} = -15 \text{ V} )</td>
<td>95</td>
<td>85</td>
<td>80</td>
<td>80</td>
<td>dB</td>
</tr>
<tr>
<td>Power supply rejection (PSRR –)</td>
<td>( V_{SS} = 15 \text{ V}, V_{SL} = -15.5 \text{ V to -14.5 V} )</td>
<td>95</td>
<td>85</td>
<td>80</td>
<td>80</td>
<td>dB</td>
</tr>
</tbody>
</table>

\(^1\) Input offset voltage is 100% tested at 25°C. It is specified by characterization and simulation over the listed temperature range.
TYPICAL CHARACTERISTICS (±15 V GRAPHS)

T_A = 25°C, G = 2, R_F = 499 Ω, R_L = 1 kΩ, Unless otherwise noted.

Figure 1.

Figure 2.

Figure 3.

Figure 4.

Figure 5.

Figure 6.

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TYPICAL CHARACTERISTICS (±15 V GRAPHS) (continued)

$T_A = 25^\circ C$, $G = 2$, $R_F = 499 \, \Omega$, $R_L = 1 \, k\Omega$, Unless otherwise noted.

**SECOND ORDER HARMONIC DISTORTION VS FREQUENCY**

![Graph 1](image1.png)

**THIRD ORDER HARMONIC DISTORTION VS FREQUENCY**

![Graph 2](image2.png)

**HARMONIC DISTORTION VS OUTPUT VOLTAGE SWING**

![Graph 3](image3.png)

**SLEW RATE VS OUTPUT VOLTAGE**

![Graph 4](image4.png)

**OPEN-LOOP GAIN VS TEMPERATURE**

![Graph 5](image5.png)

**OPEN-LOOP GAIN AND PHASE VS FREQUENCY**

![Graph 6](image6.png)

**INPUT VOLTAGE VS FREQUENCY**

![Graph 7](image7.png)

**QUIESCENT CURRENT VS SUPPLY VOLTAGE**

![Graph 8](image8.png)

**INPUT BIAS CURRENT VS TEMPERATURE**

![Graph 9](image9.png)
TYPICAL CHARACTERISTICS (±15 V GRAPHS) (continued)

\( T_A = 25°C, G = 2, R_F = 499 \, \Omega, \, R_L = 1 \, k\Omega \), Unless otherwise noted.

**INPUT OFFSET CURRENT**

\[ V_o \] vs TEMPERATURE

**INPUT OFFSET VOLTAGE**

\[ V_{io} \] vs TEMPERATURE

**OUTPUT VOLTAGE**

\[ V_O \] vs TEMPERATURE

---

**Figure 16.**

**Figure 17.**

**Figure 18.**

---

**STATIC OUTPUT DRIVE CURRENT**

\[ I_{o} \] vs TEMPERATURE

**SMALL SIGNAL TRANSIENT RESPONSE**

**LARGE SIGNAL TRANSIENT RESPONSE**

---

**Figure 19.**

**Figure 20.**

**Figure 21.**

---

**LARGE SIGNAL TRANSIENT RESPONSE**

---

**Figure 22.**

**Figure 23.**

**Figure 24.**
TYPICAL CHARACTERISTICS (±15 V GRAPHS) (continued)

$T_A = 25^\circ C$, $G = 2$, $R_F = 499 \, \Omega$, $R_L = 1 \, k\Omega$, Unless otherwise noted.

**SETTLING TIME**

**OVERDRIVE RECOVERY**

**COMMON-MODE REJECTION RATIO**

**REJECTION RATIO**

**OUTPUT IMPEDANCE**

Figure 25.

Figure 26.

Figure 27.

Figure 28.

Figure 29.

Figure 30.

Figure 31.
APPLICATION INFORMATION

INTRODUCTION
The THS4631 is a high-speed, FET-input operational amplifier. The combination of: high gain bandwidth product of 210 MHz, high slew rate of 1000 V/µs, and trimmed dc precision makes the device an excellent design option for a wide variety of applications, including test and measurement, optical monitoring, transimpedance gain circuits, and high-impedance buffers. The applications section of the data sheet discusses these particular applications in addition to general information about the device and its features.

TRANSIMPEDEANCE FUNDAMENTALS
FET-input amplifiers are often used in transimpedance applications because of their extremely high input impedance. A transimpedance block accepts a current as an input and converts this current to a voltage at the output. The high-input impedance associated with FET-input amplifiers minimizes errors in this process caused by the input bias currents, IIB, of the amplifier.

DESIGNING THE TRANSIMPEDEANCE CIRCUIT
Typically, design of a transimpedance circuit is driven by the characteristics of the current source that provides the input to the gain block. A photodiode is the most common example of a capacitive current source that interfaces with a transimpedance gain block. Continuing with the photodiode example, the system designer traditionally chooses a photodiode based on two opposing criteria: speed and sensitivity. Faster photodiodes cause a need for faster gain stages, and more sensitive photodiodes require higher gains in order to develop appreciable signal levels at the output of the gain stage.

These parameters affect the design of the transimpedance circuit in a few ways. First, the speed of the photodiode signal determines the required bandwidth of the gain circuit. Second, the required gain, based on the sensitivity of the photodiode, limits the bandwidth of the circuit. Third, the larger capacitance associated with a more sensitive signal source also detracts from the achievable speed of the gain block. The dynamic range of the input signal also places requirements on the amplifier dynamic range. Knowledge of the source output current levels, coupled with a desired voltage swing on the output, dictates the value of the feedback resistor, RF. The transfer function from input to output is VOUT = IINRF.

The large gain-bandwidth product of the THS4631 provides the capability for simultaneously achieving both high-transimpedance gain, wide bandwidth, high slew rate, and low noise. In addition, the high-power supply rails provide the potential for a very wide dynamic range at the output, allowing for the use of input sources which possess wide dynamic range. The combination of these characteristics makes the THS4631 a design option for systems that require transimpedance amplification of wideband, low-level input signals. A standard transimpedance circuit is shown in Figure 32.

Figure 32. Wideband Photodiode Transimpedance Amplifier

As indicated, the current source typically sets the requirements for gain, speed, and dynamic range of the amplifier. For a given amplifier and source combination, achievable performance is dictated by the following parameters: the amplifier gain-bandwidth product, the amplifier input capacitance, the source capacitance, the transimpedance gain, the amplifier slew rate, and the amplifier output swing. From this information, the optimal performance of a transimpedance circuit using a given amplifier is determined. Optimal is defined here as providing the required transimpedance gain with a maximized flat frequency response.

For the circuit shown in Figure 32, all but one of the design parameters is known: the feedback capacitor (CF) must be determined. Proper selection of the feedback capacitor prevents an unstable design, controls pulse response characteristics, provides maximized flat transimpedance bandwidth, and limits broadband integrated noise. The maximized flat frequency response results with CF calculated as shown in Equation 1, where CF is the feedback capacitor, RF is the feedback resistor, CS is the total source capacitance (including amplifier input capacitance and parasitic capacitance at the inverting node), and GBP is the gain-bandwidth product of the amplifier in hertz.
Once the optimal feedback capacitor has been selected, the transimpedance bandwidth can be calculated with Equation 2.

\[
F - 3dB = \frac{GBP}{2\pi R_F (C_S + C_F)}
\]

(2)

Figure 34. Transimpedance Circuit Bode Plot

The performance of the THS4631 has been measured for a variety of transimpedance gains with a variety of source capacitances. The achievable bandwidths of the various circuit configurations are summarized numerically in Table 1. The frequency responses are presented in Figure 35, Figure 36, and Figure 37.

Note that the feedback capacitances do not correspond exactly with the values predicted by the equation. They have been tuned to account for the parasitic capacitance of the feedback resistor (typically 0.2 pF for 0805 surface mount devices) as well as the additional capacitance associated with the PC board. The equation should be used as a starting point for the design, with final values for CF optimized in the laboratory.

Table 1. Transimpedance Performance Summary for Various Configurations

<table>
<thead>
<tr>
<th>SOURCE CAPACITANCE (PF)</th>
<th>TRANSM- IMPEDANCE GAIN (Ω)</th>
<th>FEEDBACK CAPACITANCE (PF)</th>
<th>-3 dB FREQUENCY (MHz)</th>
</tr>
</thead>
<tbody>
<tr>
<td>18</td>
<td>10 k</td>
<td>2</td>
<td>15.8</td>
</tr>
<tr>
<td>18</td>
<td>100 k</td>
<td>0.5</td>
<td>3</td>
</tr>
<tr>
<td>18</td>
<td>1 M</td>
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<td>1.2</td>
</tr>
<tr>
<td>47</td>
<td>10 k</td>
<td>2.2</td>
<td>8.4</td>
</tr>
<tr>
<td>47</td>
<td>100 k</td>
<td>0.7</td>
<td>2.1</td>
</tr>
<tr>
<td>47</td>
<td>1 M</td>
<td>0.2</td>
<td>0.52</td>
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<tr>
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<td>10 k</td>
<td>3</td>
<td>5.5</td>
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<td>100</td>
<td>100 k</td>
<td>1</td>
<td>1.4</td>
</tr>
<tr>
<td>100</td>
<td>1 M</td>
<td>0.2</td>
<td>0.37</td>
</tr>
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Table 1. Transimpedance Performance Summary for Various Configurations (continued)

<table>
<thead>
<tr>
<th>Frequency (Hz)</th>
<th>10-kΩ Transimpedance Gain</th>
<th>100-kΩ Transimpedance Gain</th>
<th>1-MΩ Transimpedance Gain</th>
</tr>
</thead>
<tbody>
<tr>
<td>10 kHz</td>
<td>85</td>
<td>105</td>
<td>125</td>
</tr>
<tr>
<td>1 MHz</td>
<td>75</td>
<td>95</td>
<td>115</td>
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<tr>
<td>10 MHz</td>
<td>70</td>
<td>90</td>
<td>100</td>
</tr>
<tr>
<td>100 MHz</td>
<td>65</td>
<td>85</td>
<td>90</td>
</tr>
</tbody>
</table>

**Figure 35.**

**Figure 36.**

**Figure 37.**

MEASURING TRANSIMPEDANCE BANDWIDTH

While there is no substitute for measuring the performance of a particular circuit under the exact conditions that are used in the application, the complete system environment often makes measurements harder. For transimpedance circuits, it is difficult to measure the frequency response with traditional laboratory equipment because the circuit requires a current as an input rather than a voltage. Also, the capacitance of the current source has a direct effect on the frequency response. A simple interface circuit can be used to emulate a capacitive current source with a network analyzer. With this circuit, trans-impedance bandwidth measurements are simplified, making amplifier evaluation easier and faster.

![Network Analyzer Diagram](https://www.ti.com/lit/an/slos451b/slos451b.pdf)

**Figure 38. Emulating a Capacitive Current Source With a Network Analyzer**

The transconductance transfer function of the interface circuit is:

\[
\frac{I_O(s)}{V_S(s)} = \frac{1}{2R_S \left( 1 + \frac{C_1}{C_2} \right)}
\]  

(Above the Pole Frequency)

The transfer function contains a zero at dc and a pole at: \( \frac{1}{2R_S (C_1 + C_2)} \). The transconductance is constant at: \( \frac{1}{2R_S \left( 1 + \frac{C_1}{C_2} \right)} \), above the pole frequency, providing a controllable ac-current source. This circuit also properly terminates the network analyzer with 50 \( \Omega \) at high frequencies. The second requirement for this current source is to provide the desired output impedance, emulating the output impedance of a photodiode or other current source. The output impedance of this circuit is given by:

\[
Z_O(s) = \frac{C_1 + C_2}{C_1 \times C_2} \left[ \frac{s + \frac{1}{2R_S (C_1 + C_2)}}{s + \frac{1}{2R_S C_1}} \right]
\]  

(Approx.)

Assuming \( C_1 \gg C_2 \), the equation reduces to: \( Z_O = \frac{1}{sC_2} \), giving the appearance of a capacitive source at a higher frequency.

Capacitor values should be chosen to satisfy two requirements. First, \( C_2 \) represents the anticipated capacitance of the true source. Second \( C_1 \) is chosen...
such that the corner frequency of the transconductance network is much less than the transimpedance bandwidth of the circuit. Choosing this corner frequency properly leads to more accurate measurements of the transimpedance bandwidth. If the interface circuit corner frequency is too close to the bandwidth of the circuit, determining the power level in the flatband is difficult. A decade or more of flat bandwidth provides a good basis for determining the proper transimpedance bandwidth.

**ALTERNATIVE TRANSIMPEDANCE CONFIGURATIONS**

Other transimpedance configurations are possible. Three possibilities are shown below.

The first configuration is a slight modification of the basic transimpedance circuit. By splitting the feedback resistor, the feedback capacitor value becomes more manageable and easier to control. This type of compensation scheme is useful when the feedback capacitor required in the basic configuration becomes so small that the parasitic effects of the board and components begin to dominate the total feedback capacitance. By reducing the resistance across the capacitor, the capacitor value can be increased. This mitigates the dominance of the parasitic effects.

The second configuration uses a resistive T-network to achieve high transimpedance gains using relatively small resistor values. This topology can be useful when the desired transimpedance gain exceeds the value of available resistors. The transimpedance gain is given by Equation 5.

\[
R_{EQ} = R_{F1} \left(1 + \frac{R_{F2}}{R_{F3}}\right)
\]

The third configuration uses a capacitive T-network to achieve fine control of the compensation capacitance. The capacitor \(C_{F3}\) can be used to tune the total effective feedback capacitance to a fine degree. This circuit behaves the same as the basic transimpedance configuration, with the effective \(C_F\) given by Equation 6.

\[
\frac{1}{C_{FEQ}} = \frac{1}{C_{F1}} \left(1 + \frac{C_{F3}}{C_{F2}}\right)
\]
SUMMARY OF KEY DECISIONS IN TRANSIMPEDANCE DESIGN

The following is a simplified process for basic transimpedance circuit design. This process gives a start to the design process, though it does ignore some aspects that may be critical to the circuit.

**STEP 1:** Determine the capacitance of the source.

**STEP 2:** Calculate the total source capacitance, including the amplifier input capacitance, \( C_{\text{in}}(\text{CM}) \) and \( C_{\text{in}}(\text{DIFF}) \).

**STEP 3:** Determine the magnitude of the possible current output from the source, including the minimum signal current anticipated and maximum signal current anticipated.

**STEP 4:** Choose a feedback resistor value such that the input current levels create the desired output signal voltages, and ensure that the output voltages can accommodate the dynamic range of the input signal.

**STEP 5:** Calculate the optimum feedback capacitance using Equation 1.

**STEP 6:** Calculate the bandwidth given the resulting component values.

**STEP 7:** Evaluate the circuit to determine if all design goals are satisfied.

SELECTION OF FEEDBACK RESISTORS

Feedback resistor selection can have a significant effect on the performance of the THS4631 in a given application, especially in configurations with low closed-loop gain. If the amplifier is configured for unity gain, the output should be directly connected to the inverting input. Any resistance between these two points interacts with the input capacitance of the amplifier and causes an additional pole in the frequency response. For nonunity gain configurations, low resistances are desirable for flat frequency response. However, care must be taken not to load the amplifier too heavily with the feedback network if large output signals are expected. In most cases, a trade off is made between the frequency response characteristics and the loading of the amplifier. For a gain of 2, a 499-Ω feedback resistor is a suitable operating point from both perspectives. If resistor values are chosen too large, the THS4631 is subject to oscillation problems. For example, an inverting amplifier configuration with a 5-kΩ gain resistor and a 5-kΩ feedback resistor develops an oscillation due to the interaction of the large resistors with the input capacitance. In low gain configurations, avoid feedback resistors this large or anticipate using an external compensation scheme to stabilize the circuit. Using a simple capacitor in parallel with the feedback resistor makes the amplifier more stable as shown in the Typical Characteristics graphs.

NOISE ANALYSIS

High slew rate, unity gain stable, voltage-feedback operational amplifiers usually achieve their slew rate at the expense of a higher input noise voltage. The 7 nV/√Hz input voltage noise for the THS4631 is, however, much lower than comparable amplifiers while achieving high slew rates. The input-referred voltage noise, and the input-referred current noise term, combine to give low output noise under a wide variety of operating conditions. Figure 42 shows the amplifier noise analysis model with all the noise terms included. In this model, all noise terms are taken to be noise voltage or current density terms in either nV/√Hz or fA/√Hz.

![Figure 42. Noise Analysis Model](image)

The total output noise voltage can be computed as the square root of all square output noise voltage contributors. Equation 7 shows the general form for the output noise voltage using the terms shown in Figure 42.

\[
E_O = \sqrt{E_{NI}^2 + (I_{BN}R_S)^2 + 4kTR_S^2 + (I_{Bi}R_f)^2 + 4kTR_f^2 \text{NG}}
\]

(7)

Dividing this expression by the noise gain \( \text{NG} = (1 + \frac{R_f}{R_g}) \) gives the equivalent input-referred noise voltage at the noninverting input, as shown in Equation 8:

\[
E_N = \sqrt{E_{NI}^2 + (I_{BN}R_S)^2 + 4kTR_S^2 + \left(\frac{I_{Bi}R_f}{\text{NG}}\right)^2 + 4kTR_f^2 \frac{\text{NG}}{\text{NG}}}
\]

(8)

Using high resistor values can dominate the total equivalent input-referred noise. Using a 3-kΩ source-resistance \( R_S \) value adds a voltage noise term of approximately 7 nV/√Hz. This is equivalent to the amplifier voltage noise term. Using higher resistor...
values dominate the noise of the system. Although
the THS4631 JFET input stage is ideal for
high-source impedance because of the low-bias
currents, the system noise and bandwidth is limited
by a high-source (R_s) impedance.

SLEW RATE PERFORMANCE WITH VARYING
INPUT STEP AMPLITUDE AND RISE/FALL
TIME

Some FET input amplifiers exhibit the peculiar
behavior of having a larger slew rate when presented
with smaller input voltage steps and slower edge
rates due to a change in bias conditions in the input
stage of the amplifier under these circumstances.
This phenomena is most commonly seen when FET
input amplifiers are used as voltage followers. As this
behavior is typically undesirable, the THS4631 has
been designed to avoid these issues. Larger
amplitudes lead to higher slew rates, as would be
anticipated, and fast edges do not degrade the slew
rate of the device. The high slew rate of the THS4631
allows improved SFDR and THD performance,
especially noticeable above 5 MHz.

PRINTED-CIRCUIT BOARD LAYOUT
TECHNIQUES FOR OPTIMAL
PERFORMANCE

Achieving optimum performance with high frequency
amplifier-like devices in the THS4631 requires careful
attention to board layout parasitic and external
component types.

Recommendations that optimize performance include:

- Minimize parasitic capacitance to any ac ground
  for all of the signal I/O pins. Parasitic capacitance
  on the output and input pins can cause instability.
  To reduce unwanted capacitance, a window
  around the signal I/O pins should be opened in all
  of the ground and power planes around those
  pins. Otherwise, ground and power planes should
  be unbroken elsewhere on the board.

- Minimize the distance (< 0.25") from the power
  supply pins to high frequency 0.1-µF and 100-pF
de-coupling capacitors. At the device pins, the
ground and power plane layout should not be in
close proximity to the signal I/O pins. Avoid
narrow power and ground traces to minimize
inductance between the pins and the de-coupling
capacitors. The power supply connections should
always be de-coupled with these capacitors.
Larger (6.8 µF or more) tantalum de-coupling
capacitors, effective at lower frequency, should
also be used on the main supply pins. These may
be placed somewhat farther from the device and
may be shared among several devices in the
same area of the PC board.

- Careful selection and placement of external
  components preserve the high frequency
  performance of the THS4631. Resistors should be
  a very low reactance type. Surface-mount
  significant time constants that can degrade
  layout. Again, keep their leads and PC board
  board may be made with short direct traces or
  surface-mount resistors have approximately 0.2
  2.0 kΩ 6-dB signal loss intrinsic to a doubly-terminated
  gain-setting resistors. Even with a low parasitic
  pF in shunt with the resistor. For resistor values
  on the outputs are necessary. Low parasitic
  and/or a zero that can effect circuit operation.
  network components, such as input termination
  resistors, should be placed close to the
gain-setting resistors. Even with a low parasitic
capacitance shunting the external resistors,
excessively high resistor values can create
significant time constants that can degrade
performance. Good axial metal-film or
surface-mount resistors have approximately 0.2
pF in shunt with the resistor. For resistor values >
2.0 kΩ, this parasitic capacitance can add a pole
and/or a zero that can effect circuit operation.
Keep resistor values as low as possible,
consistent with load driving considerations.

- Connections to other wideband devices on the
  board may be made with short direct traces or
  through onboard transmission lines. For short
  connections, consider the trace and the input to
  the next device as a lumped capacitive load.
  Relatively wide traces (50 mils to 100 mils) should
  be used, preferably with ground and power planes
  opened up around them. Estimate the total
  capacitive load and determine if isolation resistors
  on the outputs are necessary. Low parasitic
  capacitive loads (< 4 pF) may not need an RS
  since the THS4631 is nominally compensated
to operate with a 2-pF parasitic load. Higher parasitic
  capacitive loads without an RS are allowed as the
  signal gain increases (increasing the unloaded
  phase margin). If a long trace is required, and the
  6-dB signal loss intrinsic to a doubly-terminated
  transmission line is acceptable, implement a
  matched impedance transmission line using
  microstrip or stripline techniques (consult an ECL
  design handbook for microstrip and stripline layout
techniques).

A 50-Ω environment is not necessary onboard, and
in fact, a higher impedance environment improves
distortion as shown in the distortion versus load
plots. With a characteristic board trace impedance
based on board material and trace dimensions, a
matching series resistor into the trace from the
output of the THS4631 is used as well as a
terminating shunt resistor at the input of the
destination device. Remember also that the
terminating impedance is the parallel combination
of the shunt resistor and the input impedance of
the destination device: this total effective
impedance should be set to match the trace
impedance. If the 6-dB attenuation of a doubly terminated transmission line is unacceptable, a long trace can be series-terminated at the source end only. Treat the trace as a capacitive load in this case. This does not preserve signal integrity or a doubly-terminated line. If the input impedance of the destination device is low, there is some signal attenuation due to the voltage divider formed by the series output into the terminating impedance.

- Socketing a high-speed part like the THS4631 is not recommended. The additional lead length and pin-to-pin capacitance introduced by the socket creates a troublesome parasitic network which makes it almost impossible to achieve a smooth, stable frequency response. Best results are obtained by soldering the THS4631 part directly onto the board.

PowerPAD DESIGN CONSIDERATIONS

The THS4631 is available in a thermally-enhanced PowerPAD family of packages. These packages are constructed using a downset leadframe upon which the die is mounted [see Figure 43 (a) and Figure 43 (b)]. This arrangement results in the lead frame being exposed as a thermal pad on the underside of the package [see Figure 43 (c)]. Because this thermal pad has direct thermal contact with the die, excellent thermal performance can be achieved by providing a good thermal path away from the thermal pad.

The PowerPAD package allows for both assembly and thermal management in one manufacturing operation. During the surface-mount solder operation (when the leads are being soldered), the thermal pad can also be soldered to a copper area underneath the package. Through the use of thermal paths within this copper area, heat can be conducted away from the package into either a ground plane or other heat dissipating device.

The PowerPAD package represents a breakthrough in combining the small area and ease of assembly of surface mount with the mechanical methods of heatsinking.

Figure 43. Views of Thermally Enhanced Package

Although there are many ways to properly heatsink the PowerPAD package, the following steps illustrate the recommended approach.

PowerPAD PCB LAYOUT CONSIDERATIONS

1. PCB with a top side etch pattern is shown in Figure 44 and Figure 45. There should be etch for the leads and for the thermal pad.

2. Place the recommended number of holes in the area of the thermal pad. These holes should be 10 mils in diameter. Keep them small so that solder wicking through the holes is not a problem during reflow.

3. Additional vias may be placed anywhere along the thermal plane outside of the thermal pad area. This helps dissipate the heat generated by the THS4631 IC. These additional vias may be larger than the 10-mil diameter vias directly under the thermal pad. They can be larger because they are not in the thermal pad area to be
soldered so that wicking is not a problem.

4. Connect all holes to the internal ground plane. Although the PowerPAD is electrically isolated from all pins and the active circuitry, connection to the ground plane is recommended. This is due to the fact that ground planes on most PCBs are typically the targets copper area. Offering the best thermal path heat to flow out of the device.

5. When connecting these holes to the ground plane, do not use the typical web or spoke via connection methodology. Web connections have a high thermal resistance connection that is useful for slowing the heat transfer during soldering operations. This makes the soldering of vias that have plane connections easier. In this application, however, low thermal resistance is desired for the most efficient heat transfer. Therefore, the holes under the THS4631 PowerPAD package should make their connection to the internal ground plane with a complete connection around the entire circumference of the plated-through hole.

6. The top-side solder mask should leave the terminals of the package and the thermal pad area with its via holes exposed. The bottom-side solder mask should cover the via holes of the thermal pad area. This prevents solder from being pulled away from the thermal pad area during the reflow process.

7. Apply solder paste to the exposed thermal pad area and all of the IC terminals.

8. With these preparatory steps in place, the IC is simply placed in position and run through the solder reflow operation as any standard surface-mount component. This results in a part that is properly installed.

POWER DISSIPATION AND THERMAL CONSIDERATIONS

To maintain maximum output capabilities, the THS4631 does not incorporate automatic thermal shutoff protection. The designer must take care to ensure that the design does not violate the absolute maximum junction temperature of the device. Failure may result if the absolute maximum junction temperature of 150°C is exceeded. For best performance, design for a maximum junction temperature of 125°C. Between 125°C and 150°C, damage does not occur, but the performance of the amplifier begins to degrade. The thermal characteristics of the device are dictated by the package and the PC board. Maximum power dissipation for a given package can be calculated using Equation 9.

\[ P_{D_{\text{max}}} = \frac{T_{\text{max}} - T_A}{\theta_{JA}} \]

where:

- \( P_{D_{\text{max}}} \) is the maximum power dissipation in the amplifier (W).
- \( T_{\text{max}} \) is the absolute maximum junction temperature (°C).
- \( T_A \) is the ambient temperature (°C).
- \( \theta_{JA} = \theta_{JC} + \theta_{CA} \)
  - \( \theta_{JC} \) is the thermal coefficient from the silicon junctions to the case (°C/W).
  - \( \theta_{CA} \) is the thermal coefficient from the case to ambient air (°C/W).

NOTE:

For systems where heat dissipation is more critical, the THS4631 is offered in an 8-pin MSOP with PowerPAD package and an 8-pin SOIC with PowerPAD package with better thermal performance. The thermal coefficient for the PowerPAD packages are substantially improved over the traditional SOIC. Maximum power dissipation levels are depicted in Figure 46 for the available packages. The data for the PowerPAD packages assume a board layout that follows the PowerPAD layout guidelines referenced above and detailed in the PowerPAD application note number SLMA002. Figure 46 also illustrates the effect of not soldering the PowerPAD to a PCB. The thermal impedance increases substantially which may cause serious heat and performance issues. Be sure to always solder the PowerPAD to the PCB for optimum performance.

![Figure 46. Maximum Power Dissipation vs. Ambient Temperature](image-url)
Results are with no air flow and PCB size = 3" x 3"

\[ \theta_{JA} = 58.4^\circ \text{C/W} \] for the 8-pin MSOP with PowerPAD (DGN).

\[ \theta_{JA} = 98^\circ \text{C/W} \] for the 8-pin SOIC high-K test PCB (D).

\[ \theta_{JA} = 158^\circ \text{C/W} \] for the 8-pin MSOP with PowerPAD, without solder.

When determining whether or not the device satisfies the maximum power dissipation requirement, it is important to not only consider quiescent power dissipation, but also dynamic power dissipation. Often times, this is difficult to quantify because the signal pattern is inconsistent, but an estimate of the RMS power dissipation can provide visibility into a possible problem.

**DESIGN TOOLS EVALUATION FIXTURE, SPICE MODELS, AND APPLICATIONS SUPPORT**

Texas Instruments is committed to providing its customers with the highest quality of applications support. To support this goal an evaluation board has been developed for the THS4631 operational amplifier. The board is easy to use, allowing for straightforward evaluation of the device. The evaluation board can be ordered through the Texas Instruments web site, www.ti.com, or through your local Texas Instruments sales representative. The board layers are provided in Figure 47, Figure 48, and Figure 49. The bill of materials for the evaluation board is provided in Table 2.
## BILL OF MATERIALS

### Table 2. THS4631DDA EVM

<table>
<thead>
<tr>
<th>ITEM</th>
<th>DESCRIPTION</th>
<th>SMD SIZE</th>
<th>PCB DESIGNATOR</th>
<th>PCQNTY</th>
<th>MANUFACTURER'S PART NUMBER(1)</th>
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<tr>
<td>1</td>
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<td>C3, C6</td>
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<td></td>
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<td>(TI) THS4631DDA</td>
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(1) The manufacturer's part numbers are used for test purposes only.

### EVM

Computer simulation of circuit performance using SPICE is often useful when analyzing the performance of analog circuits and systems. This is particularly true for video and RF-amplifier circuits where parasitic capacitance and inductance can have a major effect on circuit performance. A SPICE model for the THS4631 is available through either the Texas Instruments web site (www.ti.com). These models help in predicting small-signal ac and transient performance under a wide variety of operating conditions. They are not intended to model the distortion characteristics of the amplifier, nor do they attempt to distinguish between the package types in their small-signal ac performance. Detailed information about what is and is not modeled is contained in the model file itself.
Figure 50. THS4631 EVM Schematic
ADDITIONAL REFERENCE MATERIAL

- *PowerPAD Made Easy*, application brief (SMA004)
- *PowerPAD Thermally Enhanced Package*, technical brief (SLMA002)
- *Noise Analysis of FET Transimpedance Amplifiers*, application bulletin, Texas Instruments Literature Number SBOA060.
- *Tame Photodiodes With Op Amp Bootstrap*, application bulletin, Texas Instruments Literature Number SBBA002.
- *Designing Photodiode Amplifier Circuits With OPA128*, application bulletin, Texas Instruments Literature Number SBOA061.

EVM WARNINGS AND RESTRICTIONS

It is important to operate this EVM within the input and output voltage ranges as specified in the table provided below.

<table>
<thead>
<tr>
<th>Input Range, $V_{S+}$ to $V_{S-}$</th>
<th>10 V to 30 V</th>
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<td>Input Range, $V_I$</td>
<td>10 V to 30 V NOT TO EXCEED $V_{S+}$ or $V_{S-}$</td>
</tr>
<tr>
<td>Output Range, $V_O$</td>
<td>10 V to 30 V NOT TO EXCEED $V_{S+}$ or $V_{S-}$</td>
</tr>
</tbody>
</table>

Exceeding the specified input range may cause unexpected operation and/or irreversible damage to the EVM. If there are questions concerning the input range, please contact a TI field representative prior to connecting the input power.

Applying loads outside of the specified output range may result in unintended operation and/or possible permanent damage to the EVM. Consult the product data sheet or EVM user's guide (if user's guide is available) prior to connecting any load to the EVM output. If there is uncertainty as to the load specification, please contact a TI field representative.

During normal operation, some circuit components may have case temperatures greater than 30°C. The EVM is designed to operate properly with certain components above 50°C as long as the input and output ranges are maintained. These components include but are not limited to linear regulators, switching transistors, pass transistors, and current sense resistors. These types of devices can be identified using the EVM schematic located in the material provided. When placing measurement probes near these devices during operation, please be aware that these devices may be very warm to the touch.

Mailing Address: Texas Instruments Post Office Box 655303 Dallas, Texas 75265
REVISION HISTORY

Changes from Original (December 2004) to Revision A

• Changed the Related FET Input Amplifier Products table ................................................................. 1
• Changed the Differential input resistance value From: $10^9 || 6.5$ To: $10^9 || 3.9$ ........................................... 4
• Changed the Common-mode input resistance value From: $10^9 || 6.5$ To: $10^9 || 3.9$ ................................ 4
• Changed Figure 8 - From: $R_L = 499\Omega$ To $R_F = 499\Omega$ ............................................................... 6
• Changed Figure 9 - From: $R_L = 499\Omega$ To $R_F = 499\Omega$ ............................................................... 6
• Added Figure 23 ..................................................................................................................................... 7
• Added Figure 24 ..................................................................................................................................... 7
• Added Figure 50 ..................................................................................................................................... 19

Changes from Revision A (March 2005) to Revision B

• Changed the $T_{stg}$ value in the Absolute Maximum Ratings table From: 65°C to 150°C To: –65°C to 150°C ................. 2
### PACKAGING INFORMATION

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<thead>
<tr>
<th>Orderable Device</th>
<th>Status</th>
<th>Package Type</th>
<th>Package Drawing</th>
<th>Pins</th>
<th>Package Qty</th>
<th>Eco Plan</th>
<th>Lead/Ball Finish</th>
<th>MSL Peak Temp</th>
<th>Op Temp (°C)</th>
<th>Device Marking</th>
<th>Samples</th>
</tr>
</thead>
<tbody>
<tr>
<td>THS4631D</td>
<td>ACTIVE</td>
<td>SOIC</td>
<td>D</td>
<td>8</td>
<td>75</td>
<td>Green (RoHS &amp; no Sb/Br)</td>
<td>CU NIPDAU</td>
<td>Level-2-260C-1 YEAR</td>
<td>-40 to 85</td>
<td>4631</td>
<td>Samples</td>
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<tr>
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<td>SO PowerPAD</td>
<td>DDA</td>
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<td>-40 to 85</td>
<td>4631</td>
<td>Samples</td>
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<td>Level-2-260C-1 YEAR</td>
<td>-40 to 85</td>
<td>4631</td>
<td>Samples</td>
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<tr>
<td>THS4631DGN</td>
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<td>80</td>
<td>Green (RoHS &amp; no Sb/Br)</td>
<td>CU NIPDAU</td>
<td>Level-1-260C-UNLIM</td>
<td>-40 to 85</td>
<td>ADK</td>
<td>Samples</td>
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<td>80</td>
<td>Green (RoHS &amp; no Sb/Br)</td>
<td>CU NIPDAUAG</td>
<td>Level-1-260C-UNLIM</td>
<td>-40 to 85</td>
<td>ADK</td>
<td>Samples</td>
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<td>DGN</td>
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<td>2500</td>
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<td>CU NIPDAU</td>
<td>Level-1-260C-UNLIM</td>
<td>-40 to 85</td>
<td>ADK</td>
<td>Samples</td>
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<td>Level-1-260C-UNLIM</td>
<td>-40 to 85</td>
<td>ADK</td>
<td>Samples</td>
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<td>D</td>
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<td>2500</td>
<td>Green (RoHS &amp; no Sb/Br)</td>
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<td>Level-2-260C-1 YEAR</td>
<td>-40 to 85</td>
<td>4631</td>
<td>Samples</td>
</tr>
</tbody>
</table>

(1) The marketing status values are defined as follows:
- **ACTIVE:** Product device recommended for new designs.
- **LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
- **NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
- **PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.
- **OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substances do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
- **RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
- **Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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### TAPE AND REEL INFORMATION

**REEL DIMENSIONS**

![Reel Diameter Diagram]

**TAPE DIMENSIONS**

![TAPE DIMENSIONS Diagram]

<table>
<thead>
<tr>
<th>A0</th>
<th>B0</th>
<th>K0</th>
<th>W</th>
<th>P1</th>
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</thead>
<tbody>
<tr>
<td>Dimension designed to accommodate the component width</td>
<td>Dimension designed to accommodate the component length</td>
<td>Dimension designed to accommodate the component thickness</td>
<td>Overall width of the carrier tape</td>
<td>Pitch between successive cavity centers</td>
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</tbody>
</table>

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**

![Pocket Quadrants Diagram]

*All dimensions are nominal*

<table>
<thead>
<tr>
<th>Device</th>
<th>Package Type</th>
<th>Package Drawing</th>
<th>Pins</th>
<th>SPQ</th>
<th>Reel Diameter (mm)</th>
<th>Reel Width W1 (mm)</th>
<th>A0 (mm)</th>
<th>B0 (mm)</th>
<th>K0 (mm)</th>
<th>P1 (mm)</th>
<th>W (mm)</th>
<th>Pin1 Quadrant</th>
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<td>DGN</td>
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<td>5.3</td>
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<td>D</td>
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<td>5.2</td>
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## TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal*

<table>
<thead>
<tr>
<th>Device</th>
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<th>Package Drawing</th>
<th>Pins</th>
<th>SPQ</th>
<th>Length (mm)</th>
<th>Width (mm)</th>
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<td>2500</td>
<td>350.0</td>
<td>350.0</td>
<td>43.0</td>
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</tbody>
</table>
Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.
DDA (R-PDSO-G8) PowerPAD™ PLASTIC SMALL-OUTLINE

MECHANICAL DATA

NOTES:
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5–1994.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0.15.
D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <http://www.ti.com>.
E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
F. This package complies to JEDEC MS-012 variation BA

PowerPAD is a trademark of Texas Instruments.

Texas Instruments
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THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

NOTE: A. All linear dimensions are in millimeters

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NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC-7351 is recommended for alternate designs.
D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http://www.ti.com>. Publication IPC-7351 is recommended for alternate designs.
E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.
NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion.
D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <http://www.ti.com>.
E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
F. Falls within JEDEC MO-187 variation AA–T

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NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

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6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.
NOTES: (continued)

10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

11. Board assembly site may have different recommendations for stencil design.
NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
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NOTES: (continued)

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